

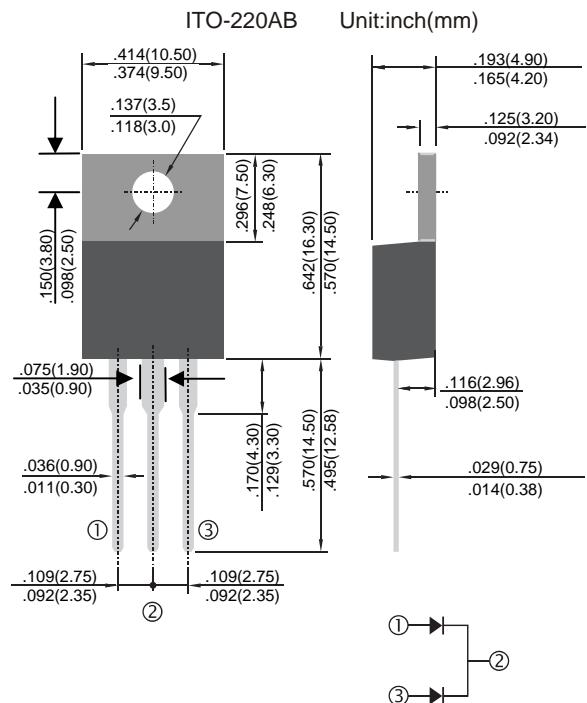


YEA SHIN TECHNOLOGY CO., LTD

MBRL3040FCT THRU MBRL30150FCT

30A Low V_F SCHOTTKY Barrier Rectifier**Voltage - 40 to 150 Volts Current – 30 Amperes****Features**

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0.
- Flame Retardant Epoxy Molding Compound.
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency.
- High current capability
- For use in low voltage, high frequency inverters free wheeling, and polarity protection applications.
- Lead free in comply with EU RoHS.

**Mechanical Data**

- Case: ITO-220AB molded plastic
- Terminals: solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: As marked.
- Mounting Position: Any

Maximum Ratings & Thermal Characteristics (Ratings at 25°C ambient temperature unless otherwise specified.)
(Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate by 20%).

Parameters	Symbol	MBRL 3040FCT	MBRL 3045FCT	MBRL 3060FCT	MBRL 30100FCT	MBRL 30150FCT	Unit
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	40	45	60	100	150	V
Maximum RMS Voltage	V _{RMS}	28	31.5	42	70	105	V
Maximum DC Blocking Voltage	V _{DC}	40	45	60	100	150	V
Maximum Average Froward Rectified Current	I _(AV)			30			A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}			250			A
Maximum Instantaneous Forward Voltage at 15.0A Per Diode	V _F	0.55	0.6	0.7	0.87		V
Maximum DC Reverse Current Ta=25°C at Rated DC Blocking Voltage Ta=125°C	I _R	0.15 36 (Typ.)	0.22 16 (Typ.)	0.1 8.5 (Typ.)	0.05 3.1 (Typ.)		mA
Typical Junction Capacitance (Note 1)	C _J	1200	650	750	400		pF
Maximum Thermal Resistance (Note 2)	R _{θJC}		2				°C/W
Operating Temperature Range	T _J		-55 to +150				°C
Storage Temperature Range	T _{STG}		-55 to +150				°C

Notes: 1. Measure at 1.0MHz and applied reverse voltage of 4.0 Vdc.

2. Mounted on infinite heatsink.

DEVICE CHARACTERISTICS

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40-45V

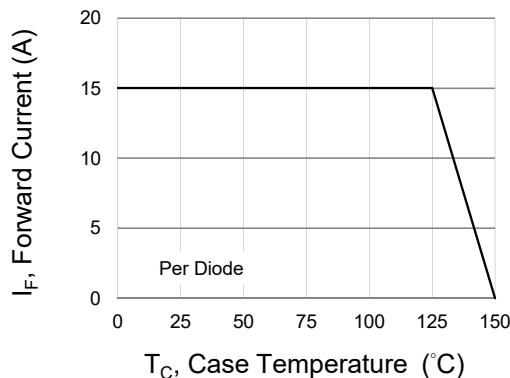


Fig.1 Forward Current Derating Curve

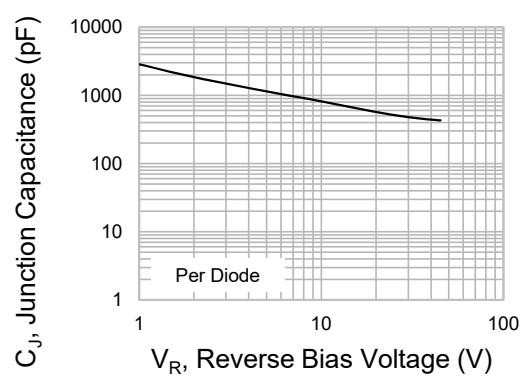
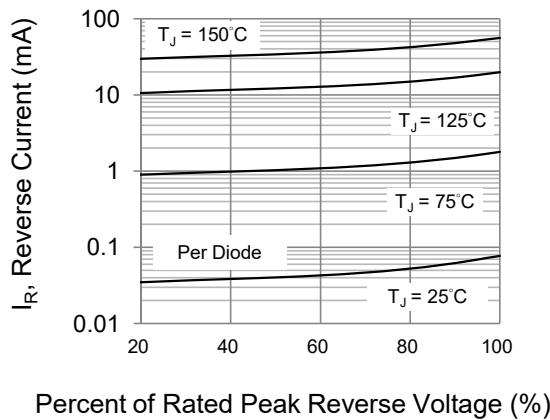
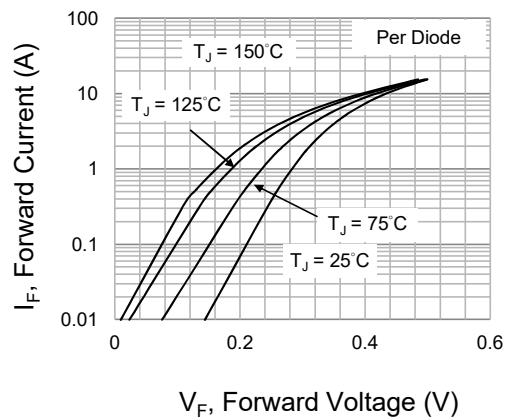


Fig.2 Typical Junction Capacitance



Percent of Rated Peak Reverse Voltage (%)

Fig.3 Typical Reverse Characteristics



V_F , Forward Voltage (V)

Fig.4 Typical Forward Characteristics

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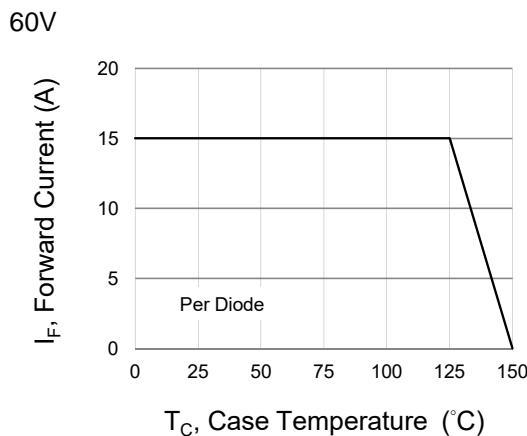


Fig.1 Forward Current Derating Curve

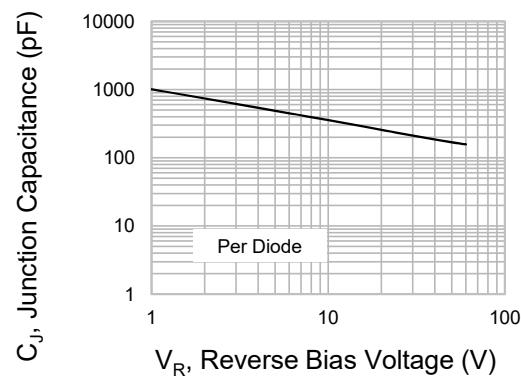


Fig.2 Typical Junction Capacitance

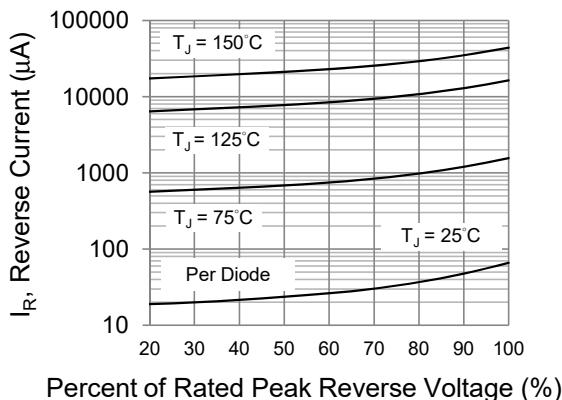


Fig.3 Typical Reverse Characteristics

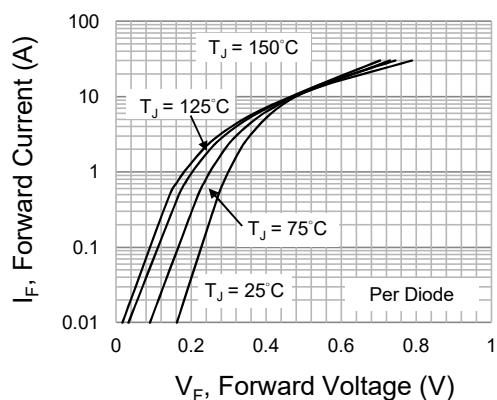


Fig.4 Typical Forward Characteristics

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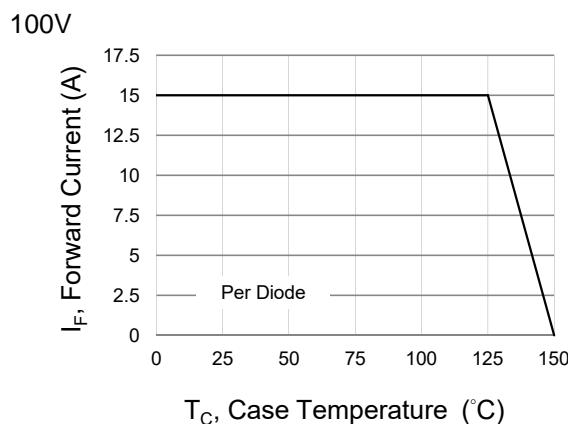


Fig.1 Forward Current Derating Curve

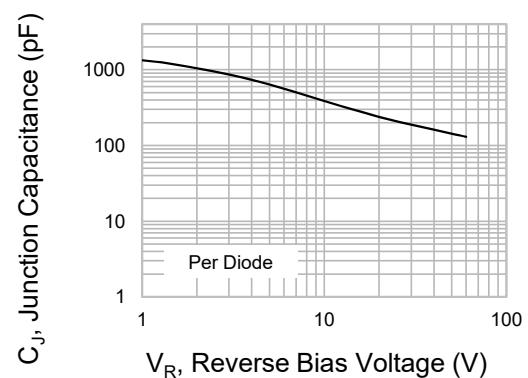


Fig.2 Typical Junction Capacitance

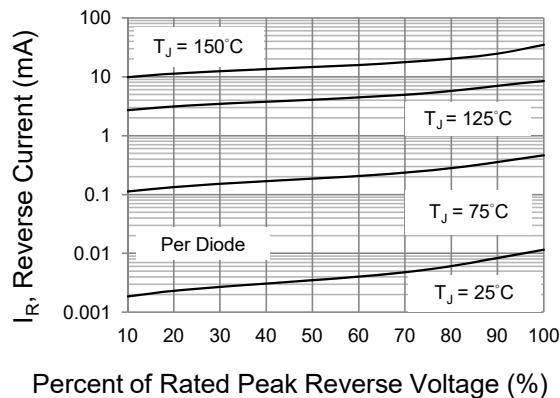


Fig.3 Typical Reverse Characteristics

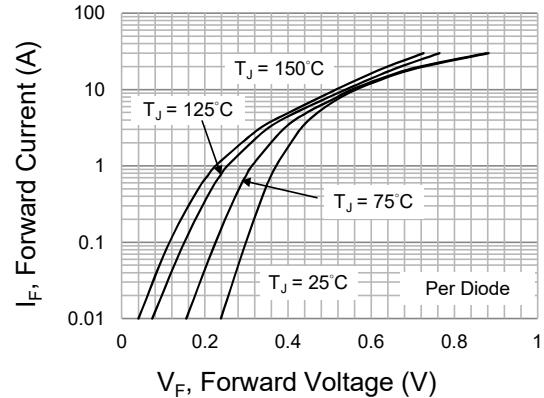


Fig.4 Typical Forward Characteristics

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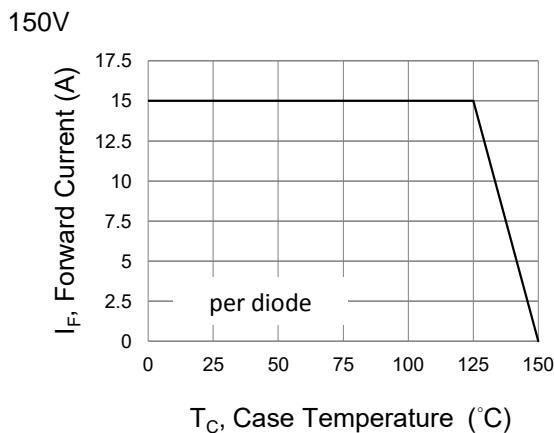


Fig.1 Forward Current Derating Curve

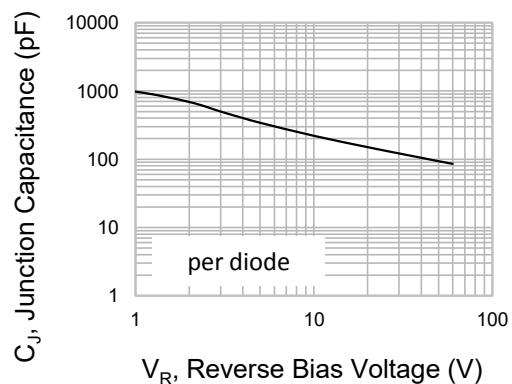


Fig.2 Typical Junction Capacitance

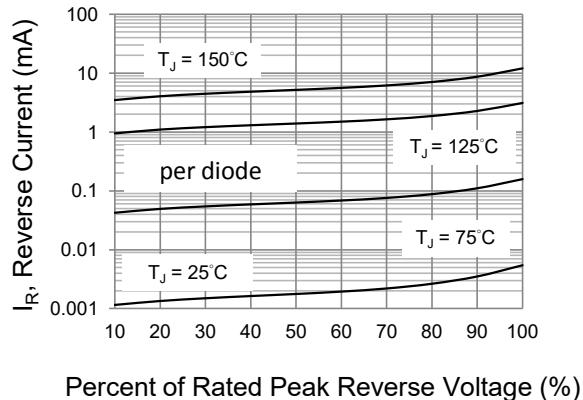


Fig.3 Typical Reverse Characteristics

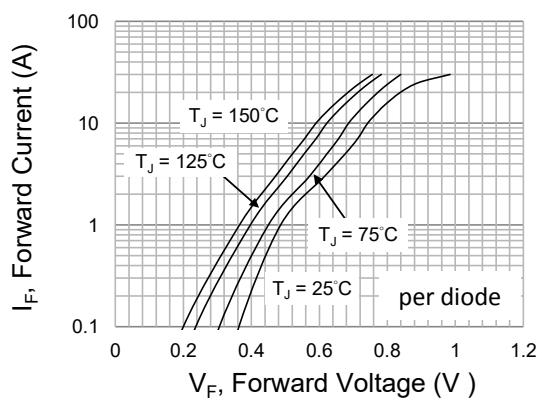


Fig.4 Typical Forward Characteristics